

BASiC

B1D08065KS

MGT **A** Manufacturer Group of Technology

650V 🛦 8A 🛦 SIC SCHOTTKY DIODE

SILICON CARBIDE SIC SCHOTTKY DIODE ▲ THT type Excellent surge capability Easy paralleling due to positive V_F temperature coefficient Temperature independent switching Low forward voltage

TO-220 ISO-2L ceramic package ▲ 2.5kV isolation voltage





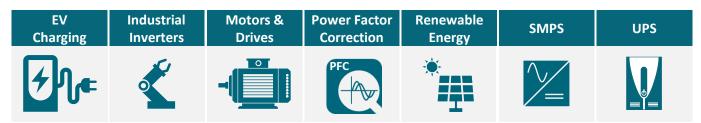
RoHS

REACH

SPECIFICATION

Item (T _c = 25°C, unless otherwise noted)		Characteristics
Operating Temperature Range	TJ	-55°C to +175°C
Storage Temperature Range	Ts	-55°C to +175°C
Repetitive Peak Reverse Voltage	V _{RRM}	650V
Continuous Forward Current at T _c = 145°C	I _F	8A
Total Capacitive Charge (TJ = 25°C)	Qc	24nC
Capacitance Stored Energy (V _R = 400V)	Ec	6μJ
Diode Forward Voltage (T _J = 175° C, I _F = 8A)	VF	1.73V
Power Dissipation	Ρ _{ΤΟΤ}	74W

APPLICATIONS



PIN DESCRIPTION

Circuit Diagram	Outline - Front View	Pin No.	Description
		1 2	Cathode Anode

B1D08065KS A Rev.001 A Date: 30/09/2022 A Page: 1

Copyright by MGT A www.mgt.co.com A All rights reserved A The information in this document is subject to change without notice.



ABSOLUT MAXIMUM RATINGS **A** T_C = 25°C, unless otherwise noted

Item	Condition	Symbol		Unit
Repetitive Peak Reverse Voltage		V _{RRM}	650	V
Non-Repetitive Peak Reverse Voltage		V _{RSM}	650	V
Continuous Forward Current	T _C = 25°C	I _F	22	А
Continuous Forward Current	T _C = 145°C	IF	8	А
Non-Repetitive Forward Surge Current	T_{C} = 25°C, t_{p} = 10ms, Half Sine Wave	I _{FSM}	64	А
I ² t Value	T _c = 25°C, t _p = 10ms	∫i²dt	20.48	A ² s
Power Dissipation	T _C = 25°C	P _{TOT}	74	W
Power Dissipation	T _C = 110°C	P _{TOT}	32	W
Operating Junction Temperature		TJ	-55 to +175	°C
Storage Temperature Range		T _{STG}	-55 to +175	°C
Isolation Voltage	AC, t = 1s		2500	V _{RMS}
TO-220 Mounting Torque	M3 Screw		0.7	Nm

ELECTRICAL CHARACTERISTICS

ltem	Condition	Symbol	Min.	Тур.	Max.	Unit
Static Characteristics						
DC Blocking Voltage	T _J = 25°C	V _{DC}	650			V
Diode Forward Voltage	I _F = 8A, T _J = 25°C	V _F		1.46		V
Diode Forward Voltage	I _F = 8A, T _J = 175°C	V _F		1.73		V
Reverse Current	V _R = 650V, T _J = 25°C	I _R		1		μΑ
Reverse Current	V _R = 650V, T _J = 175°C	I _R		10		μA
Item	Condition	Symbol	Min.	Тур.	Max.	Unit
Dynamic Characteristics						
	V _R = 400V, T _J = 25°C					
Total Capacitive Charge	$Q_C = \int_0^{V_R} C(V) dV$	Q _C		24		nC
Total Capacitance	$V_{R} = 1V$, f = 1MHz, T _J = 25°C	С		365		рF
Total Capacitance	V _R = 300V, f = 1MHz, T _J = 25°C	С		41.1		pF
Total Capacitance	$V_{R} = 600V, f = 1MHz, T_{J} = 25^{\circ}C$	С		40.7		pF
Capacitance Stored Energy	V _R = 400V, T _J = 25°C	Ec		6		μ

THERMAL RESISTANCE PERFORMANCE

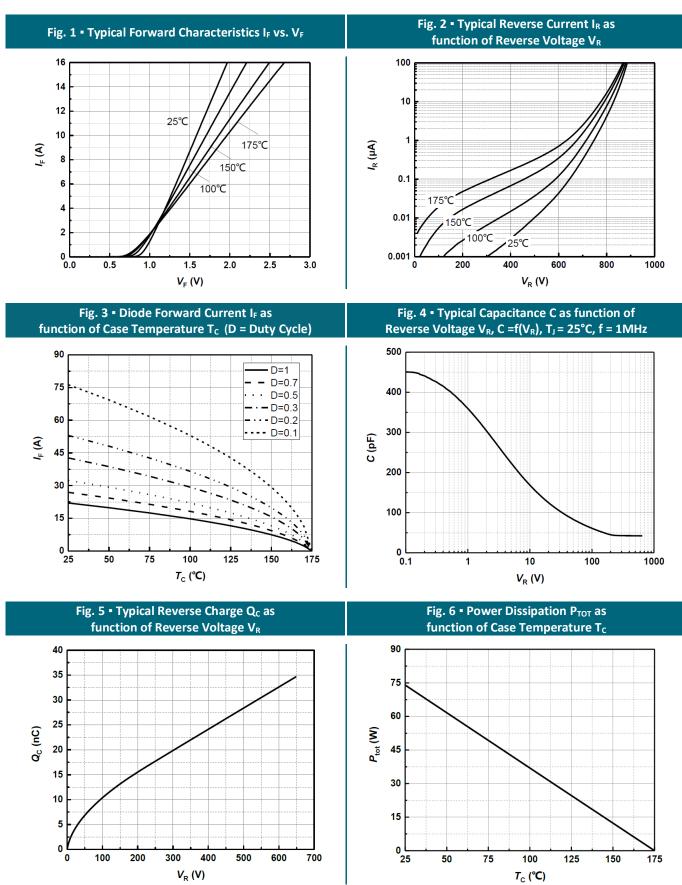
Item	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance, Junction to Case	$R_{\theta,JC}$		2.020		K/W

Copyright by MGT **A** www.mgt.co.com **A** All rights reserved **A** The information in this document is subject to change without notice.



MGT 🔺 Manufacturer Group of Technology

REFERENCE DATA ▲ TYPICAL PERFORMANCE

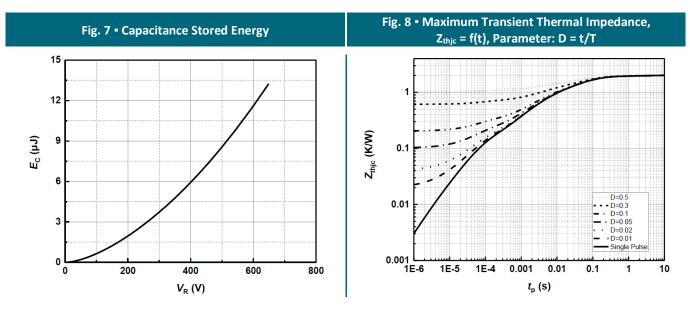


B1D08065KS A Rev.001 Date: 30/09/2022 Page: 3

Copyright by MGT A www.mgt.co.com A All rights reserved A The information in this document is subject to change without notice.

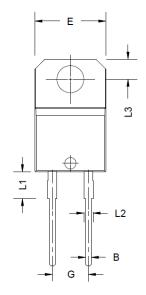


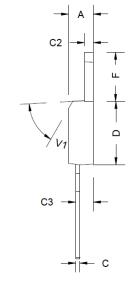
REFERENCE DATA A TYPICAL PERFORMANCE

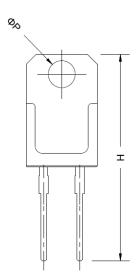




PACKAGE OUTLINE







Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)	Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
А	4.40	4.50	4.60	G		5.08 BSC	
В	0.61	0.75	0.88	Н	28.00	28.90	29.80
С	0.46	0.58	0.70	L1	-	3.75	-
C2	1.21	1.265	1.32	L2	1.14	-	1.70
С3	2.40	2.56	2.72	L3	2.65	2.80	2.95
D	8.60	9.15	9.70	V1	-	45°	-
E	9.80	10.10	10.40	ØР	-	-	3.88
F	6.55	6.75	6.95				

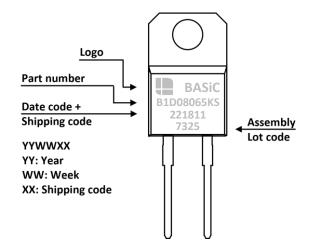
TO-220 ISO-2L package ▲ Epoxy meets UL94-V0

ORDERING INFORMATION

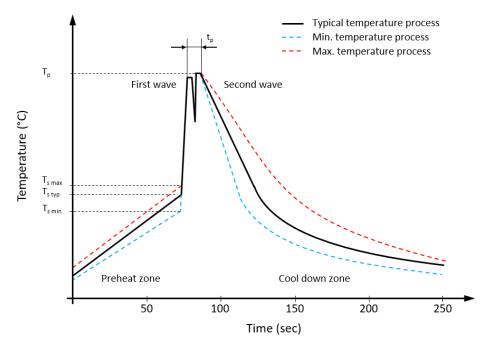
Part Number	Package	Packing	Tube Qty.	Inner Box Qty.	Outer Box Qty.
B1D08065KS	TO-220 ISO-2L	Tube	50pcs	500pcs	5,000pcs

SILICON CARBIDE (SiC) SCHOTTKY DIODE ▲ B1D08065KS

PART MARKING



RECOMMENDED WAVE SOLDERING PROFILE ▲ THT PACKAGE



Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

Profile Features		Value 🛦 Sn-Pb Assembly	Value 🔺 Pb-free Assembly
Preheat temperature min.	T_{smin}	100 °C	100 °C
Preheat temperature typical	T _{s typ}	120 °C	120 °C
Preheat temperature max.	$T_{s max}$	130 °C	130 °C
Preheat time t_s from $T_{s min}$ to $T_{s max}$	ts	70 seconds	70 seconds
Peak temperature	Tp	235 °C to 260 °C	245 °C to 260 °C
Time of actual peak temperature	t _p	Max. 10 seconds Max. 5 second each wave	Max. 10 seconds Max. 5 second each wave
Ramp-down date min.		~ 2 °C/second	~ 2 °C/second
Ramp-down rate typical		~ 3.5 °C/second	~ 3.5 °C/second
Ramp-down rate max.		~ 5 °C/second	~ 5 °C/second
Time 25°C to 25°C		4 minutes	4 minutes

MGT 🔺 Manufacturer Group of Technology

B1D08065KS A Rev.001 A Date: 30/09/2022 A Page: 6

Copyright by MGT **A** www.mgt.co.com **A** All rights reserved **A** The information in this document is subject to change without notice.

BASiC



REVISION TABLE

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

DISCLAIMER

Except for the written expressed warranties, MGT does not implicitly, by assumption or whatever else, warrant, under-take, promise any other warranty or guaranty for any MGT product.

All information and technical specifications made available by MGT are for guidance only and we reserve the right to change or modify them without prior notice. Unless expressly stated in writing by MGT, we reject any guarantees, obligations, or warranties.

All MGT products with the technical specifications described are suitable for use in certain applications. Operating, production, storage and environmental conditions can have a massive influence on the parameters mentioned in the data sheets, which cause the performance to vary over time.

It is subject to the user's duty of care to design and validate his products in such a way that appropriate measures are taken, such as protective circuits or redundant systems to ensure the safety standards required in the application.

MGT components are not designed or rated for use in life support, rescue, safety critical, military, or aerospace applications where failure or malfunction could result in property or environmental damage, serious injury or death. In the aforementioned cases, please contact us before using MGT products.

In principle, we reserve all rights and MGT's general terms and conditions apply. You can find them on our website <u>www.mgt.co.com.</u>